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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/676,862	09/30/2003	Kenneth So	10519/112	7636
7590 03/09/2005 EXAMI		NER		
Brinks Hofer Gilson & Lione			LAM, DAVID	
P.O. Box 10395 Chicago, IL 6			ART UNIT PAPER NUMBER	
Omougo, IE	0010		2827	
			DATE MAILED: 03/09/2005	j

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)				
	10/676,862	SO ET AL.				
Office Action Summary	Examiner	Art Unit				
	David Lam	2827				
The MAILING DATE of this communication a Period for Reply	appears on the cover sheet t	with the correspondence addre	ss			
A SHORTENED STATUTORY PERIOD FOR REITHE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a - If NO period for reply is specified above, the maximum statutory perions for reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the may be arrived patent term adjustment. See 37 CFR 1.704(b).	N. 2.1.136(a). In no event, however, may a reply within the statutory minimum of the iod will apply and will expire SIX (6) MC atute, cause the application to become a	a reply be timely filed airty (30) days will be considered timely. DNTHS from the mailing date of this comm ABANDONED (35 U.S.C. § 133).	unication.			
Status						
1) Responsive to communication(s) filed on	,					
	his action is non-final.					
•	Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) ⊠ Claim(s) <u>1-34</u> is/are pending in the application 4a) Of the above claim(s) is/are without 5) ⊠ Claim(s) <u>1-20 and 28-34</u> is/are allowed. 6) ⊠ Claim(s) <u>21-27</u> is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction and	drawn from consideration.					
Application Papers						
9) The specification is objected to by the Exam	iner.					
10) The drawing(s) filed on is/are: a) a	accepted or b) Objected to	by the Examiner.				
Applicant may not request that any objection to t	the drawing(s) be held in abey	ance. See 37 CFR 1.85(a).				
Replacement drawing sheet(s) including the corn 11) The oath or declaration is objected to by the						
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for fore a) All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the p application from the International Bur * See the attached detailed Office action for a light	ents have been received. ents have been received in priority documents have bee reau (PCT Rule 17.2(a)).	Application No n received in this National Sta	ıge			
Attachment(s)		ş .				
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)		Summary (PTO-413) o(s)/Mail Date				
 Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/Paper No(s)/Mail Date 12/03, 1/05. 		Informal Patent Application (PTO-15	(2)			
S. Patent and Trademark Office						

DETAILED ACTION

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 21-22, 24-25, 27 are rejected under 35 U.S.C. 102(b) as being anticipated by 1. Passcuccit et al. (5,276,644).

Regarding to claims 21-22, 24-25, 27, Passcuccit et al. discloses a non-volatile memory comprising: a two-dimension memory array including a memory cell comprising temperaturedependent behavior; a current sensing amplifier (SA) coupled with the memory cell; a set of memory cells couple with the current sensing amplifier, the set of memory cells generating a current reference (I_{vr}) when a voltage is applied to the set of memory cells; wherein the current Application/Control Number: 10/676,862 Page 3

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sensing amplifier compares the current reference to current sensed back from the memory cell during a read operation to determine whether the memory cell is programmed; a programmable mirror (CM2) interposed between the set of memory cells and the current sensing amplifier, wherein the memory cell is a write-many memory cell. *See Figs. 2-3; Cols. 4-5*.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 23, 26 are rejected under 35 U.S.C. 103(a) as being unpatentable over Passcuccit et al. (5,276,644) in view of Scheuerlein (6,545,898).

Regarding to claims 23, 26, Passcuccit et al. disclose the claimed invention as noted above but lack an inclusion of wherein the memory cell is a write-once memory cell and part of a three-dimensional memory array. Scheuerlein discloses a memory device comprising three-dimensional array (100) comprises write-once memory cell. It would have been obvious to one having ordinary skill in the art at the time of the invention to modify by utilizing Scheuerlein's teach to form a three-dimensional write-once memory array of Passcuccit et al.'s memory array to reduce leakage currents when writing and faster write time of a selected memory cell. *See Figs. 1, 10-11; Cols. 3-4, 11-13.*

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Allowable Subject Matter

3. The following is an examiner's statement of reasons for allowance: Claims 1-20, 28-34 are allowable over the prior art of record because none of the prior art whether taken singularly or in combination, especially when these limitations are considered within the specific combination claimed, to teach: a memory system comprising first and second temperature-dependent reference voltages, a voltage regulator, among others as claimed in independent claim 11, operative to generate a bit line voltage from the other of the first and second temperature-dependent reference voltages; sensing amplifier, among others as claimed in independent claim 28, coupled compares the temperature-dependent reference current comprises a positive temperature coefficient to current sensed back from the memory cell during a read operation to determined whether the memory cell is programmed. Method for temperature compensation for a memory cell comprising step of generating at least one of a first/second temperature-dependent reference voltage comprising a negative/positive temperature coefficient, and among other steps as claimed in independent claim 1.

Conclusion

- 4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.
 - Van Buskirk et al. (6,205,074) disclose a temperature compensated bias generator.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to David Lam whose telephone number is 571-272-1782. The examiner can normally be reached on 6:00-4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Hoai Ho can be reached on 571-272-1777. The fax phone numbers for the organization where this application or proceeding is assigned is (703) 872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

D. Lam

February 23, 2005

DAVID LAM DIMARRY EXAMINER